(a)
TI
T_{C1}
T_{C2}
SMD
Massless
DE
$(\Delta_U = 0.008)$
λ_{SOI}
0.1
0.08
0.06
0.04
0.02
0
Δ_{SOI} [eV]
0.012
0.008
0.004
0
0.08
0.16
λ_{SOI}
(b)
Δ_U
Δ_{SOI}
Δ [eV]
0.01
0.005
0
0.002
0.004
0.006
T [eV]
(λ_{SOI}, Δ_{SOI} [meV])
Line type
(0, 0)
(0.005, 0.3)
(0.01, 0.7)
(0.02, 1.4)
(0.04, 2.7)